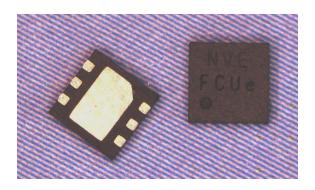
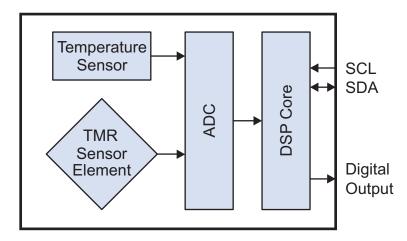


# SM324-10E TMR Smart Magnetometer



## **Block Diagram**



## **Features**

- Can detect magnets more than 50 mm away
- In-plane sensitivity—more usable than Hall sensors
- Internal temperature compensation
- I2C field measurement plus on/off digital output
- Ultraminiature 2.5 x 2.5 x 0.8 mm TDFN6 package

## **Key Specifications**

- 0 to ±20 Oe magnetic field operating range
- Ultra accurate—±0.3% of full scale at 25°C
- 1.5 mA typical supply current
- 300 samples/second
- $-40^{\circ}$ C to  $+125^{\circ}$ C operating range

## **Applications**

- · Proximity sensors
- · Noncontact current sensing
- Automotive applications
- Robotics
- Internet of Things (IoT) end nodes

## **Description**

The SM324 Smart Magnetometer provides ultraprecise magnetic field measurements.

The sensor combines a precise Tunneling Magnetoresistance (TMR) sensor element with sophisticated digital signal processing. The digital signal processing improves accuracy and allows application-specific calibration. Calibration coefficients are stored in an internal nonvolatile memory.

Unlike awkward, old-fashioned Hall-effect sensors, TMR is sensitive in-plane for optimal current sensing and easy mechanical interfaces. TMR also provides more sensitivity, higher precision, and lower noise than Hall.

An I<sup>2</sup>C interface provides data as well as a programming interface. A digital output provides precise, programmable magnetic thresholds.

Designed for harsh industrial or automotive environments, the SM324 has robust ESD protection and full -40°C to +125°C operating temperature range.





## **Absolute Maximum Ratings**

Parameter	Min.	Max.	Units
Supply voltage	-0.4	3.63	Volts
Input/ Output voltages (SCL, SDA, Digital Out)	-0.5	$V_{\rm DD} + 0.5$	Volts
Storage temperature	-50	130	°C
ESD (Human Body Model)	4000		Volts
Applied magnetic field		Unlimited	Oe





# **Operating Specifications**

Parameter	Symbol	Min.	Тур.	Max.	Units	Test Condition
Operating temperature	$T_{MIN}; T_{MAX}$	-40		125	°C	
Supply voltage	$V_{\scriptscriptstyle DD}$	1.68		3.6	V	
			1.5	2.5	mA	Active; $T_{MIN}$ to $T_{MAX}$
Supply current ( $V_{DD} = 3.3 \text{ V}$ )	$I_{\scriptscriptstyle  m DD}$		20	250	nA	Idle Mode; ≤ 85°C
			50	750	nA	Idle Mode; ≤ 125°C
Power-Up and Power-down						
Power-on reset low voltage	$V_{BOR}$	0		0.2	V	
Power down time (duration below $V_{BOR}$ )	$t_{BOR}$	3			μs	
Power-on reset rising slope	$SR_{VDD}$	10			V/ms	
Start-up time	$t_{ST1}$			1	ms	V <sub>DD</sub> ramp time to active communication
Start-up time	t <sub>st2</sub>			2.5	ms	V <sub>DD</sub> ramp time to active operation
Wake-up time	$t_{wu1}$			0.5	ms	Idle to active communication
wake-up time	$t_{ m WU2}$			2	ms	Idle to active operation
Internal Temperature Sensor						
Temperature resolution	$T_{\text{res}}$		0.003		°K/LSB	$T_{MIN}$ to $T_{MAX}$
Magnetic Measurements						
Operating magnetic field strength	Н			20	Oe	
Conversion rate	$f_{con}$	270	300		S/s	
Accuracy				±0.3 ±1	%FS	$\frac{25^{\circ}\text{C}}{\text{T}_{\text{MIN}} \text{ to } \text{T}_{\text{MAX}}}$
Hysteresis				0.1	%FS	$T_{MIN}$ to $T_{MAX}$
Output resolution				24	bits	
Digital Output						
Update rate	$\mathrm{f}_{\scriptscriptstyle \mathrm{UPDATE}}$		300		S/s	During repeated 0xAA commands
Sink current	$I_{\text{SOURCE}}$		10		mA	$V_{DD} = 3.3V$
Source current	$I_{sink}$		10		mA	$V_{OL} < 0.5V; V_{OH} > 2.8V$
Low-level analog output voltage	$V_{OL}$	0		50	mV	$I_{L} = -50 \ \mu A$
High-level analog output voltage	$V_{\text{OH}}$	$V_{DD} - 0.05$		$ m V_{\scriptscriptstyle DD}$	V	$I_L = 50 \mu A$
Nonvolatile Memory						
Write time			5	16	msec	
Endurance		1000	10000		cycles	
Thermal Characteristics						
Junction-to-ambient thermal resistance	$\theta_{\scriptscriptstyle \mathrm{JA}}$		320		°C/W	
Package power dissipation			500		mW	
I <sup>2</sup> C Interface						
Data transfer rate	DR			400 k 3.4 M	Baud	Standard mode I2C fast mode
Bus voltage	$V_{\scriptscriptstyle BUS}$	3		$V_{DD} + 0.5$	V	
Low level input threshold voltage	$V_{\scriptscriptstyle \rm IL}$	0.8			V	
High level input threshold voltage	$V_{\text{IH}}$			2.2	V	
Low level output current	$I_{OL}$	3		mA		$V_{OL}=0.4V$
Capacitive load	C <sub>B</sub>			400	pF	
I/O capacitance	$C_{\text{I/O}}$			10	pF	



## **SM324 Overview**

The SM324 is a non-contact magnetometer designed for proximity or current sensing.

The heart of the SM324 is a tunneling magnetoresistive (TMR) sensor. With a tiny 2.5 x 2.5 mm TDFN package and typical 1.5 mA active supply current and 50 nA idle current, the SM324 is the smallest, lowest-power magnetometer in its class.

Factory calibration for gain and offset, plus temperature correction and digital linearization provide extraordinary accuracy of  $\pm 0.3\%$  of full scale. Combined with a high-sensitivity TMR element, absolute accuracy is 0.12 Oe at 25°C, or 0.4 Oe from -40°C to 125°C.

The unique TMR element also yield negligible hysteresis of less than 0.1%, or 0.04 Oe from -40°C to 125°C.

#### **SM324 Operation**

A block diagram is shown below:

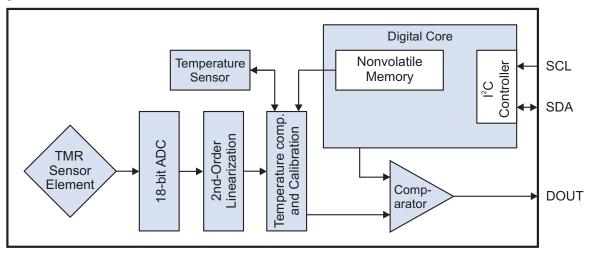


Figure 1. Detailed block diagram.

A robust 18-bit ADC, second-order linearization, and temperature compensation provide ultra-precise magnetic field measurements.

The digital core provides three bytes (24 bits) of mathematical precision.

Two outputs are available: an industry-standard I<sup>2</sup>C output for interfacing directly to microcontrollers and FPGAs, and a simple digital output for threshold detection of proximity, fault, overcurrent, and saturating magnetic fields.

Several other parameters can be programmed into the SM324 through the I<sup>2</sup>C interface.



#### **User Defined Memory**

Twenty-six 16-bit blocks of nonvolatile memory are available for part identification or general purpose use. This number can be overwritten if needed. Note that the nonvolatile memory is subject to endurance limitations and should only be used for occasionally updated data.

## Sensor Offset

The sensor core of the SM324 is factory calibrated for highest accuracy, and a programmable three-byte parameter, OFFS, is available for user adjustments to environments with non-zero magnetic fields. OFFS has a signed sign/magnitude form value with where the most-significant bit is the sign (1 = negative), and the range is  $\pm 50\%$  of the  $\pm 20$  Oe full-scale range.

## Internal Temperature Sensor

The SM324 utilizes an internal temperature sensor to allow for compensation of temperature effects. The thermometer is factory calibrated and a user-programmable three-byte variable, TEMP, is available for additional temperature offset calibration. Similar to the OFFS parameter, TEMP has a sign/magnitude form where the most-significant bit is the sign (1 = negative), and the range is  $\pm 50\%$  of the  $165^{\circ}$ C full-scale range.

## **Digital Output for Threshold Detection**

The SM324 has a programmable digital output that can be configured for threshold detection. The output is programmable usind two 24-bit threshold parameters (THRSH1 and THRSH2). THRSH1 and THRSH2 are unsigned integers, each representing 0 to 100% of full scale, where 50% is zero field, 0 is the low end of the range (-20 Oe), and 0xFFFFFF is the high end of the range (+20 Oe).

## Digital Threshold Updating

DOUT updates automatically with each sample in the Cyclic Mode, although the refresh rate is limited to eight samples per second in that mode. In normal mode, DOUT updates with each data request, so the sensor must be connected to a I<sup>2</sup>C Master actively requesting data for the output to work.

## Digital Threshold Modes

The digital output can be programmed as a high-field, low field, or window comparator function. The configuration of the output can also be reversed with a two-bit parameter, so either a high-field or low-field output can be generated. The figures below show the outputs for the three comparator modes, which are set by the CONFIG parameter.

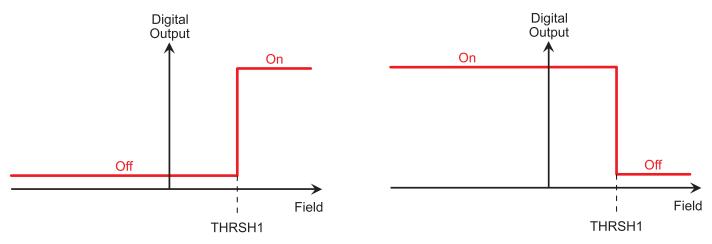


Fig. 2a. Normal mode (CONFIG = 01 bin).

Fig. 2b. Inverted mode (CONFIG = 10 bin).



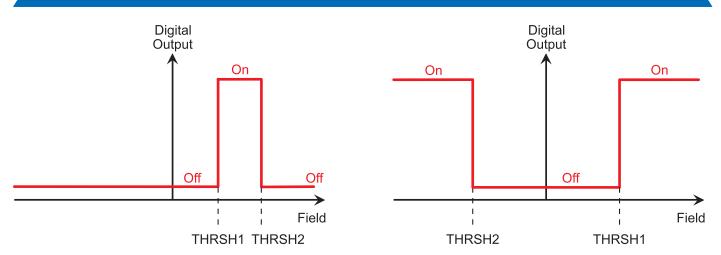


Fig. 2c. Window mode (CONFIG = 11 bin; THRSH2>THRSH1).

Fig. 2d. Inverted Window mode (CONFIG= 11; THRSH1>THRSH2).

These graphs are with respect to magnetic field, with zero field at the y-axis intercept in the center of the x-axis. The I<sup>2</sup>C output is unsigned, with zero field corresponding to 50%.

The Digital Threshold Modes are summarized in the following table:

CONFIG (Bin)	DOUT
01	0: Measurement < THRSH1
U1	1: Measurement > THRSH1
10	0: Measurement > THRSH1
10	1: Measurement < THRSH1
	Output determined by threshold settings.
	If THRSH1 > THRSH2
	1: Measurement > THRSH1 OR Measurement < THRSH2
11	0: THRSH1 > Measurement > THRSH2
	If THRSH2 > THRSH1
	1: THRSH1 < Measurement < THRSH2
	0: Measurement > THRSH2 OR Measurement < THRSH1

Table 1. Digital Output (DOUT) Threshold Configuration

The Window mode (CONFIG = 11) can be used to provide a response independent of polarity. For example, the default settings of CONFIG = 11, THRSH1 = 75% (0xC00000), and THRSH2 = 25% (0x400000) cause DOUT to be high if the field magnitude is more than 10 Oe (i.e., greater than +10 Oe or less than -10 Oe) as shown in the following diagram:

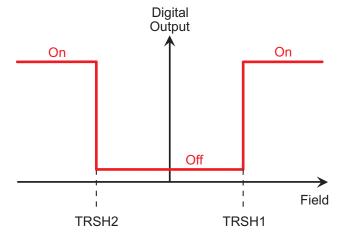


Fig. 2e. Default DOUT configuration (CONFIG = 11; THRSH1 = 75%; THRSH2 = 25%; for ominpolar DOUT).



## **Position Sensing**

A typical proximity sensor using an SM324-10E sensor and magnet is shown below. With a 4 Oe operate point, the sensor actuates with a rare-earth magnet at more than 50 mm (two inches) from the sensor:

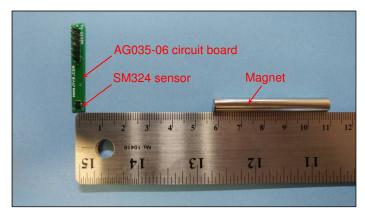


Figure 3. The SM324-10E sensor can be activated by a magnet more than 50 mm away. Maximum sensitivity is in plane with the sensor, with the magnet axis in the pin 2 to pin 5 sensor axis.

Thresholds even lower than 4 Oe can be programmed for the SM324-10E, although care must be taken to account for the earth's magnetic field, which is approximately 0.5 Oe.

Typical magnetic operate distances are illustrated below for an inexpensive ceramic disk magnet:

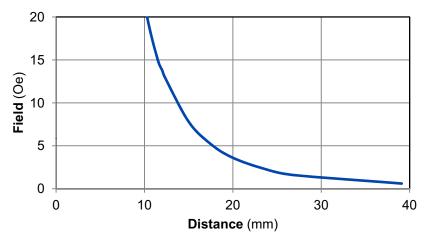


Figure 4. Field vs. distance from the center of the sensor (NVE part number 12216; ferrite magnet; d=6 mm; t=4 mm; C1/Y10T;  $M_s=B_r=2175$  G).

Larger and stronger magnets allow farther operate and release distances. For more calculations, use our axial disc magnetic field versus distance Web application at:

www.nve.com/spec/calculators.php#tabs-Axial-Disc-Magnet-Field.



## **Current Sensing**

In a typical current sensor configuration, a magnetic field provided by an off-chip current strap produces a magnetic field in the plane of the sensor. The digital output can be used for current threshold detection or overcurrent protection.

Typical current sensing configurations are shown below:



Figure 5a. 0.05" (1.3 mm) trace (0 - 5 A typ.).



Figure 5b. Five turns of 0.0055" (0.14 mm) trace (0 - 1 A typ.).

For the geometry shown below and narrow traces, the magnetic field generate can be approximated by Ampere's law:

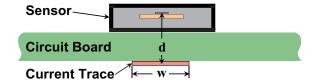


Figure 6. The geometry of current-sensing over a circuit board trace.

$$H = \frac{2I}{d}$$
 ["H" in oersteds, "I" in amps, and "d" in millimeters]

For traces on the top side of the board, "d" is simply the distance of the sensor element from the bottom of the package, which is 0.5 millimeters.

Traces on the top side of the board are typically used for currents of five amps or less. Large traces on the bottom side of the PCB can be used for currents of more than five amps.

More precise calculations can be made by breaking the trace into a finite element array of thin traces, and calculating the field from each array element. We have a free, Web-based application with a finite-element model to estimate magnetic fields and sensor outputs in this application:

www.nve.com/spec/calculators.php#tabs-Current-Sensing



## **Power-Saving Modes**

Two operational modes are available with the SM324. A normal mode allows the user to retrieve a single sensor reading via I<sup>2</sup>C and return the part to an ultra-low power idle state when communication is complete. A cyclic mode automatically updates the sensor read buffer at programmed interval. The SM324 returns to an idle state between readings. The mode of the sensor is set via an I<sup>2</sup>C command (see Table 2 below), and the cyclic interval is programmed using the CINT parameter.

A read can be performed at any time in cyclic mode, and the latest full 24-bit sensor and temperature measurement will be returned. In fact, a read from any memory address in cyclic mode will return the sensor/temp measurement. Reading or writing to memory requires a 0xBF to stop cyclic mode.

The sensor's digital threshold output is updated by single and oversample measure commands in normal mode or on the timed cadence of the cyclic measurements in cyclic mode.

Parameter Value (Binary)	Cyclic Mode Interval
000	Not assigned
001	125 msec
010	250 msec
011	500 msec
100	1000 msec
101	2000 msec
110	4000 msec
111	Not assigned

Table 2. CINT parameter values.

Command	Command Value (hex)	Notes
Read User Memory	0x20-0x38	16-bit user defined data
Write User Memory	0x60-0x78	16-bit user defined data
Checksum	0x90	Perform memory update to CHECKSUM parameter.
Single Measurement	0xAA	24-bit field plus 24-bit temperature measurement
Cyclic Measurement	0xAB	Cyclic 24-bit field plus 24-bit temperature measurement
2x Oversample Measure	0xAC	Complete 2x full continuous measurements and compute average values
4x Oversample Measure	0xAD	Complete 4x full continuous measurements and compute average values
8x Oversample Measure	0xAE	Complete 8x full continuous measurements and compute average values
16x Oversample Measure	0xAF	Complete 16x full continuous measurements and compute average values
Cyclic Measure Stop	0xBF	Stops cyclic measurements

Table 3. SM324 command options.



## Sensor Measurements and Offsets

#### Field and Temperature Measurements

The sensor provides field and temperature measurements with each reading.

The measurements are 24-bit unsign integers. 0x000000 represents the minimum value which is -20 Oe for field and -40°C for temperature. 0xFFFFFF represents full scale, which is +20 Oe for field and +125°C for temperature.

## Saturation and Overflow

All measurements responses start with a status byte followed by the data. Bit 0 of the status byte indicates when the field is too high for an accurate measurement, i.e., the sensor is saturated. In this case, Bit 0 of the status byte will be set and the field will remain at or near 0xFFFFFF.

## Offsets

Temperature and field offsets are factory calibrated, but can be reprogrammed if necessary. Offsets are in 24-bit Sign/Magnitude format, where the most significant bit (bit 23) is the sign (0 = positive; 1 = negative), and bits 22:0 are the magnitude. The offset range is  $\pm 50\%$  of full-scale, where field full-scale is  $\pm 20$  Oe; and temperature full-scale is 165°C.

Measurements and offsets are illustrated below:

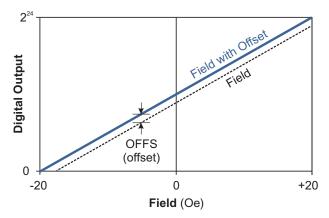


Fig. 7a. Sensor output versus field.

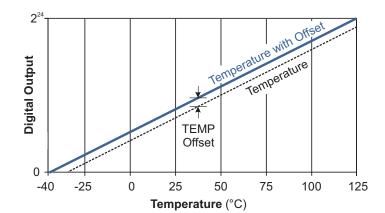


Fig. 7b. Sensor output versus temperature.



## I<sup>2</sup>C Interface

The I<sup>2</sup>C interface is an industry standard full-duplex 400 kHz connection with the sensor as the slave to an external master such as a microcontroller.

Consistent with industry practice, SDA and SCL are open-drain, and pull up resistors to  $V_{\tiny DD}$  are normally needed. The SDA / SCL pins should not be left floating for proper power-up/operation.

A schematic of a typical microcontroller interface is show in the Applications section.

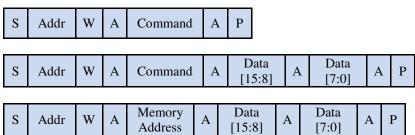
#### I<sup>2</sup>C Address

The SM324 has a seven-bit address, which can be defined in the nonvolatile memory with the  $I^2C_{ADD}$  parameter. Allowable  $I^2C$  addresses are 8 to 127. Addresses 4 to 7 are reserved for  $I^2C$  High Speed Mode. The factory default  $I^2C$  Slave Address is 16 (0x10 hex). A power cycle is required for a device to respond to an  $I^2C_{ADD}$  change.

#### Data Format

Each command follows the sequence shown below. All I<sup>2</sup>C read responses start with a status byte followed by the data. The data depends on the previous commands. Only the number of bytes that are needed for the command must be sent. An exception is the I<sup>2</sup>C High Speed Mode where three bytes must always be sent. After the execution of a command, the expected data can be read or if no data is returned by the command, the next command can be sent. You can read the same data more than once if the read request is repeated.

## Command or I<sup>2</sup>C Memory Write Sequence



## Read Sequence Following AA<sub>HEX</sub> Command

S	Addr	R	A	Status	A	Field [23:16]	A	Field [15:8]	A	Field [7:0]	A	Temp [23:16]	Α	Temp [15:8]	A	Temp [7:0]	N	P	
---	------	---	---	--------	---	---------------	---	-----------------	---	----------------	---	--------------	---	-------------	---	------------	---	---	--

## Read Sequence Following 2-byte Memory Write Command

S	Addr	R	A	Status	A	Data [15:8]	A	Data [7:0]	N	P	I
---	------	---	---	--------	---	----------------	---	---------------	---	---	---

## Key:

S/P: Start/Stop

A/N: Acknowledge / Not Acknowledge

R/W: Read (0) / Write (1)





Status Byte

A read status can be executed at any time with the following command sequence:

	S	Addr	R	Α	Status	N	P	
--	---	------	---	---	--------	---	---	--

The status byte contains the following bits:

Bit	7	6	5	4, 3	2	1	0
Meaning	0	Powered?	Busy?	00	Memory Error?	0	Saturation?

Power indication (bit 6): This bit is 1 if the sensor element is powered and 0 if not powered.

Busy indication (bit 5): This bit is 1 if the device is busy, which indicates that the data for the last command is not available yet. No new commands are processed if the device is busy. Note that the device is always busy if the cyclic measurement operation has been started.

Memory integrity/error flag (bit 2): This bit indicates whether the checksum-based integrity test passed or failed. The bit is 0 if the integrity test passed and 1 if it failed. The memory error status bit is calculated only during the power-up sequence, so a newly written CHECKSUM will only be used for memory verification and status update after a subsequent power-on reset (POR).

Saturation (bit 0): This bit is 0 for any non-measurement command or if the last command was a measurement request and the computation is valid. This bit is 1 if the last command was a measurement request and the computation caused an internal saturation or is invalid.



## **Memory Register**

The SM324 uses an internal nonvolatile memory to enable user programmable parameters such as I<sup>2</sup>C address, temperature and field offsets, digital output thresholds and configuration parameter, and cyclic mode interval. Each register is 16 bits and is written using the scheme described in the I<sup>2</sup>C interface section.

The memory address and number of bits for each parameter are also provided. Memory address bit 6 is a write bit, so writing to nonvolatile memory uses an address 0x40 higher than the address for reading.

Table 4 summarizesprogrammable parameters:

		Read Address	Write Address		Def	ault		
Parameter	Symbol	(hex)	(hex)	Bits	Hex	Value	Notes	
<b>Device Identifiers</b>								
User Memory		00-01; 20-38	40-41; 60-78	[15:0]				
I <sup>2</sup> C Address	I <sup>2</sup> C <sub>ADD</sub>	0x02	0x42	[6:0]	0x10	16 dec	Address changes require power cycle.	
Offsets								
Temperature Offset (lower 16 bits)	ТЕМР	0x18	0x58	[15:0]			Sign/Magnitude format;	
Temperature Offset (sign bit + upper 7 bits)	IEWIF	0x19	0x59	[15:8]	Fac	tory	most significant bit is sign (1=negative);	
Field Offset (lower 16 bits)	OEEG	0x17	0x57	[15:0]	Calib	orated	bits 22:0 are magnitude (±50% of full scale); full scale field = ±20 Oe;	
Field Offset (sign bit + upper 7 bits)	OFFS	0x19	0x59	[7:0]			full scale temp. = $165$ °C.	
Mode Parameters								
Cyclic Interval	CINT	0x02	0x42	[14:12]	$000_{BIN}$	0		
Digital Output Configuration								
Threshold 1 (LSB)	THRSH1	0x13	0x53	[15:0]	0x0000	10 Oe	Unsigned	
Threshold 1 (MSB)	1111/3111	0x15	0x55	[7:0]	0xC0	10 06	Unsigned (0–100%	
Threshold 2 (LSB)	THRSH2	0x14	0x54	[15:0]	0x0000	-10 Oe	of full scale)	
Threshold 2 (MSB)	111183112	0x15	0x55	[15:8]	0x40 -10 Oe		or run scarc)	
Threshold Configuration	CONFIG	0x02	0x42	[8:7]	$11_{\rm BIN}$	3		

Table 4. SM324 programmable parameters.





## **Supply and Reference Decoupling**

 $V_{\text{\tiny DD}}$  should be bypassed with a 1 nF (0.001  $\mu$ F) capacitor placed as close as possible to the supply pin. Note that a larger capacitor is not required, and could interfere with power-up timing.



## **Typical Circuit**

A typical microcontroller interface is shown below:

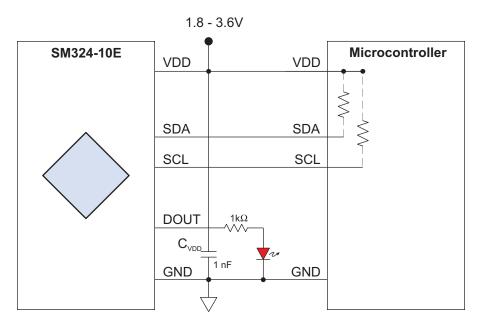


Figure 8. Typical microcontroller interface.

The SM324 is configured as a Slave and the microcontroller should be configured as the Master. The SM324 I<sup>2</sup>C interface is compatible with 1.8 to five-volt nominal microcontrollers.

The SM324 SDA and SCL lines are open-drain, so the microcontroller's internal pull-up resistor should be activated in software. If an external pull-up is used with different power supplies, it should be connected to the lower supply voltage, which is usually the sensor (Slave) supply.

 $V_{DD}$  should be bypassed with a 1 nF (0.001  $\mu$ F) capacitor placed as close as possible to the  $V_{DD}$  and GND pins.

A LED can be used to indicate the digital output. The appropriate series resistor depends on the supply voltage and LED type, and of course the LED cannot be operated at the low end of the sensor supply voltage range, such as 1.8 volts.

PIN 1

-0.30±0.05

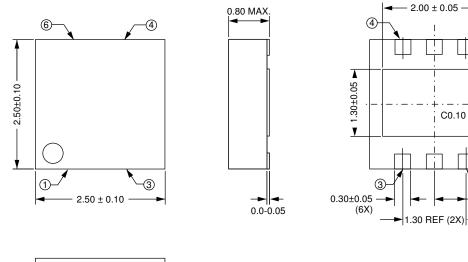
1

(4X)

0.65 TYP.



## 2.5 x 2.5 mm TDFN6 Package (approx. 15x actual size)





Pin	Symbol	Description				
1	VDD	Power Supply (bypass with a 1 nF capacitor)				
2	GND	Ground / V <sub>ss</sub>				
3	DOUT	Digital Output				
4	SCL	I <sup>2</sup> C Clock (input)				
5	SDA	I <sup>2</sup> C Data (bidirectional/open drain)				
6	NC	Not internally connected				



## **Notes:**

- Dimensions in millimeters.
- Soldering profile per JEDEC J-STD-020C, MSL 1.



## **Ordering Information**

# SM324 - 10E TR13

## **Product Family**

SM = Smart Magnetometer

## **Precision**

3 = 3-Byte resolution; TMR Sensor Element

## **Magnetic Orientation**

2 = Cross-axis (sensitive to a field vector in the pin 2 to pin 5 direction)

## Field Range

4 = 20 Oe Magnetic Field Range

## **Part Package**

10E = RoHS-Compliant 2.5 x 2.5 mm TDFN6 Package

## **Bulk Packaging**

TR13 = 13" Tape and Reel Bulk Packaging





## **Revision History**

## SB-00-077 Rev. B

February 2019

## Change

- Added charts showing field and temperature outputs (p. 10).
- More detailed descriptions of bit/byte concatenation (p. 11).
- Clearer Table 4 memory map; merged Table 5 into Table 4 (p. 13).
- Corrected minor specification inconsistencies.

## SB-00-077 Rev. A

September 2018

## Change

- Dropped "Preliminary" designation.
- Misc. style changes.
- Dropped fax number.

## **SB-00-077-PRELIM2**

August 2018

## Change

- Dropped "Product Preview" designation.
- Added 25°C accuracy specification.
- Added hysteresis specification.
- Misc. minor changes.

## **SB-00-077-PRELIM**

July 2018

## Change

• Initial release.





#### **Datasheet Limitations**

The information and data provided in datasheets shall define the specification of the product as agreed between NVE and its customer, unless NVE and customer have explicitly agreed otherwise in writing. All specifications are based on NVE test protocols. In no event however, shall an agreement be valid in which the NVE product is deemed to offer functions and qualities beyond those described in the datasheet.

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